

1.24V Programmable Shunt Voltage Reference

- Adjustable output voltage: 1.24 to 24V
- Several precision @ 25°C
 $\pm 2\%$, $\pm 1\%$, $\pm 0.5\%$ and $\pm 0.25\%$
- Sink current capability: 0.4 to 100mA
- Industrial temperature range: -40 to +125°C
- Performances compatible with industry standard TL431

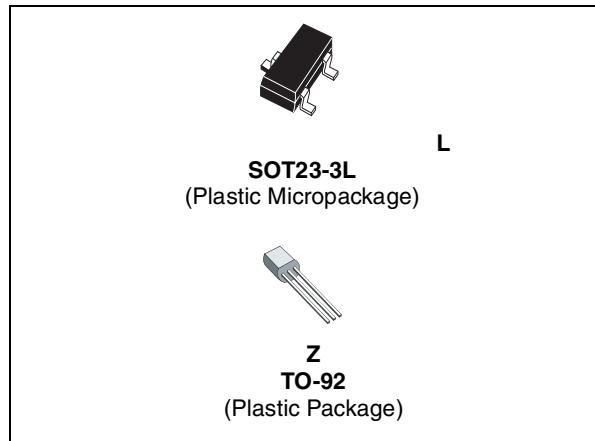
Description

The TS3431 is a programmable shunt voltage reference with guaranteed temperature stability over the entire temperature range of operation (-40 to +125°C). The output voltage may be set to any value between 1.24V and 24V with an external resistor bridge.

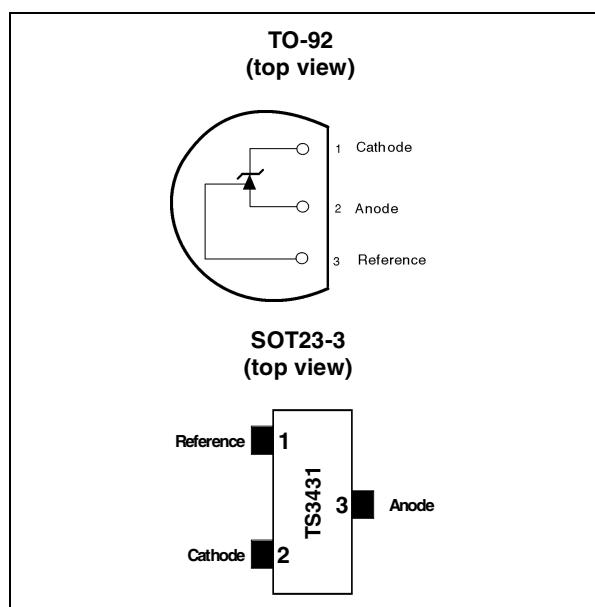
Available in SOT23-3 surface mount package, it can be designed in applications where space saving is a critical issue.

Applications

- Computers
- Instrumentation
- Battery chargers
- Switch mode power supply
- Battery operated equipments



Pin Connections (top view)



Order Codes

Part Number	Temperature Range	Package	Packaging	Marking
TS3431ILT/AILT/BILT/CILT	-40, +125°C	SOT23-3L	Tape & Reel	L280-L281 L282-L283
TS3431IZ/AIZ/BIZ/CIZ			Bulk	
TS3431IZT/AIZT/BIZT/CIZT		TO-92	Tape & Reel	
TS3431IZ-AP/AIZ-AP/BIZ-AP/CIZ-AP			Ammo pack	

1 Absolute Maximum Ratings

Table 1. Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{KA}	Cathode to Anode Voltage	25	V
I_K	Reverse Breakdown Current	-100 to +150	mA
I_{REF}	Reference Current	-0.05 to 10	mA
P_D	Power Dissipation ¹ SOT23-3 TO92	360 625	mW
T_{std}	Storage Temperature	-65 to +150	°C
ESD	Human Body Model (HBM)	2	kV
	Machine Model (MM)	200	V
Tlead	Lead Temperature (soldering, 10 seconds)	250	°C

1) P_d has been calculated with $T_{amb} = 25^\circ\text{C}$ and $T_j = 150^\circ\text{C}$ and $R_{thjc} = 66^\circ\text{C/W}$, $R_{thja} = 200^\circ\text{C/W}$ for the TO92 package
 $R_{thjc} = 110^\circ\text{C/W}$, $R_{thja} = 340^\circ\text{C/W}$ for the SOT23-3L package

Table 2. Operating Conditions

Symbol	Parameter	Value	Unit
I_K	Cathode Operating Current	0.5 to 100	mA
V_K	Cathode Operating Voltage	1.24 to 24	V
T_{oper}	Operating Free Air Temperature Range	-40 to +125	°C

2 Electrical Characteristics

Table 3. Tamb = 25°C (unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V _K	Reference input voltage I _K = 10mA	TS3431 (2%)	1.215	1.24	1.265	V
		TS3431A (1%)	1.228		1.252	
		TS3431B (0.5%)	1.234		1.246	
		TS3431C (0.25%)	1.237		1.243	
ΔV _K	Variation of reference input voltage over temperature	0°C < T < +70°C			10	mV
		-40°C < T < +105°C			18	
		-40°C < T < +125°C			21	
T _C	Temperature coefficient	-40°C < T < +125°C			100	ppm/°C
I _{KMIN}	Minimum Operating Current	T = 25°C		0.35	0.4	mA
		-40°C < T < +125°C			0.5	
$\frac{\Delta V_{ref}}{\Delta V_{ka}}$	Ratio of change in reference input voltage to change in cathode to anode voltage	I _K =10mA V _K = 24 to 1.24V		1.2	1.5	mV/V
		-40°C < T < +125°C			2	
I _{REF}	Reference input current I _K =10mA, R ₁ =10KΩ, R ₂ =+∞	T=25°C		0.9	1.5	μA
		-40°C < T < +125°C			2	
ΔI _{REF}	Reference input current deviation I _K =10mA, R ₁ =10KΩ, R ₂ =+	0°C < T < +70°C		0.5	1	μA
		-40°C < T < +125°C		0.9	1.5	
I _{OFF}	Off-state cathode current V _K =24V	T=25°C		35	500	nA
		-40°C < T < +105°C			1000	
		-40°C < T < +125°C			2000	
R _{KA}	Reverse Static Impedance	I _K = 1 to 100mA		0.2	0.4	Ω
E _N	Wideband Noise	I _K = 10mA 1kHz < f < 100kHz		100		nV/√Hz

Note: Limits are 100% production tested at 25°C. Limits over temperature are guaranteed through correlation and by design.

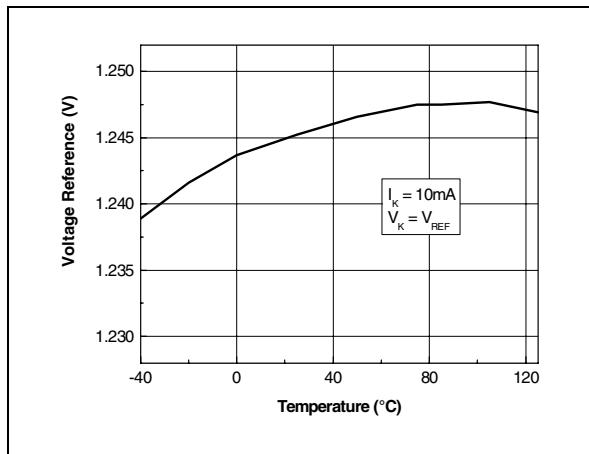
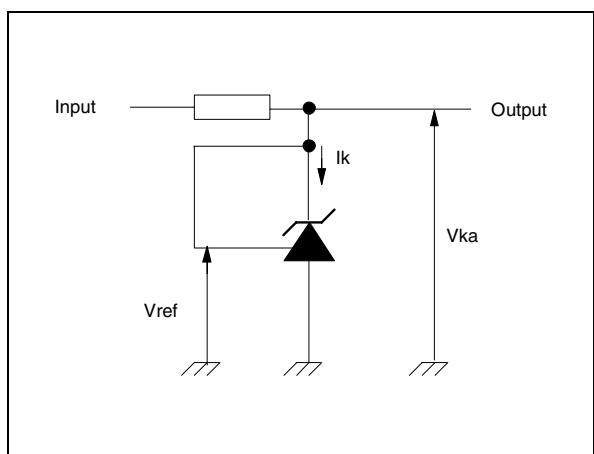
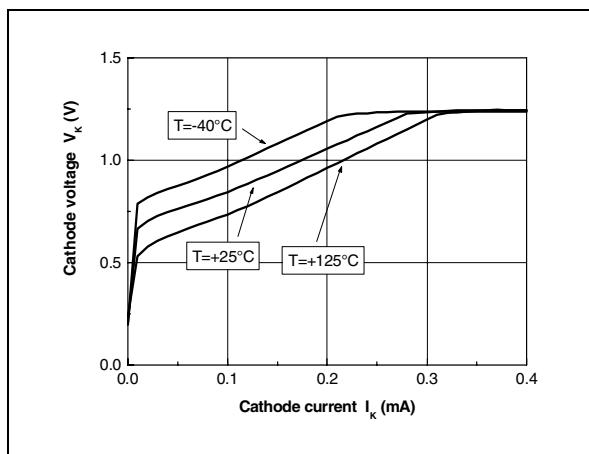
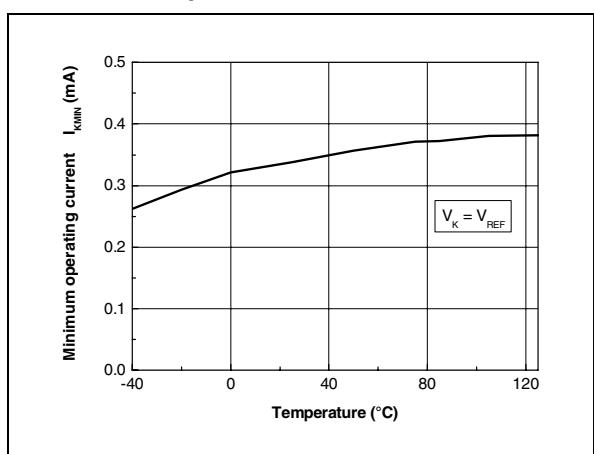
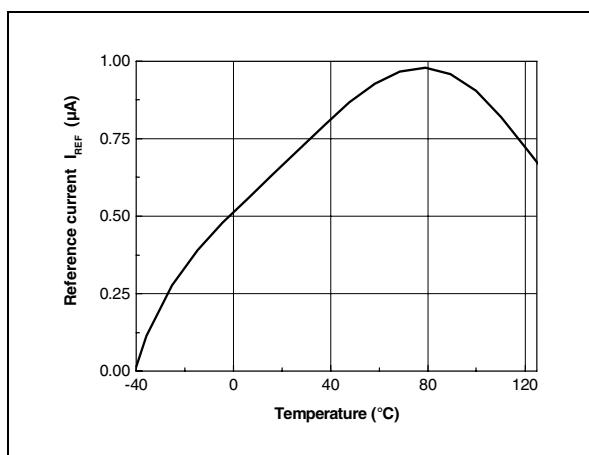
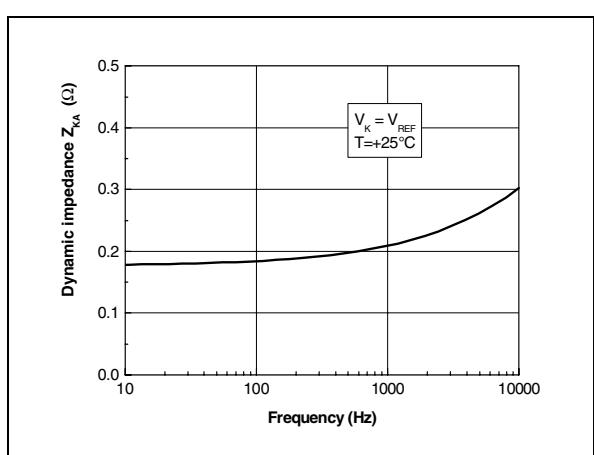
Figure 1. Reference voltage vs. temperature**Figure 4. Test circuit for $V_K = V_{\text{ref}}$** **Figure 2. Cathode voltage vs cathode current****Figure 5. Minimum operating current vs temperature****Figure 3. Reference input current vs temperature****Figure 6. Dynamic impedance vs frequency**

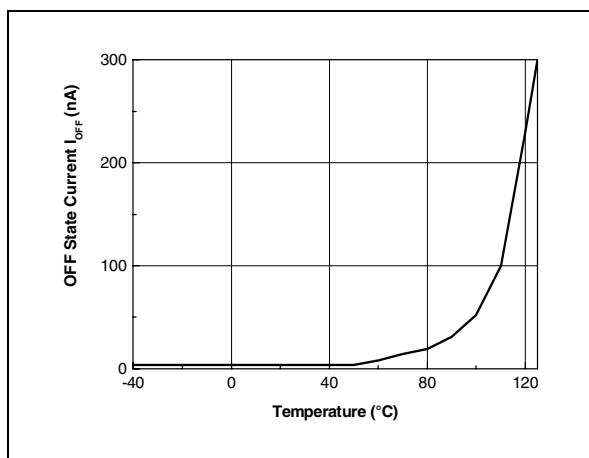
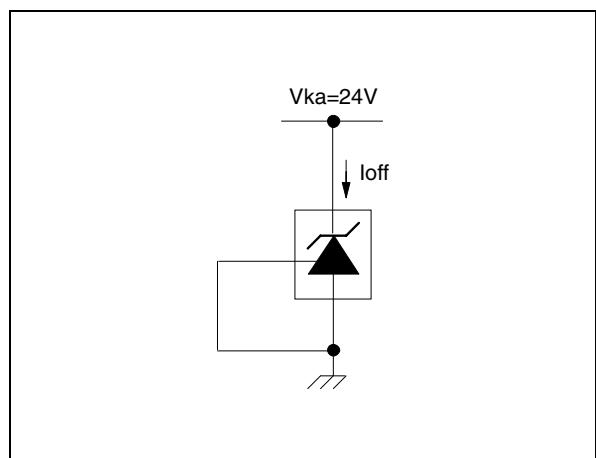
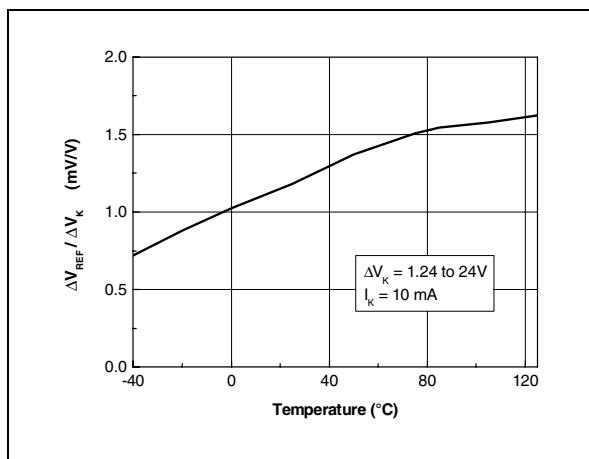
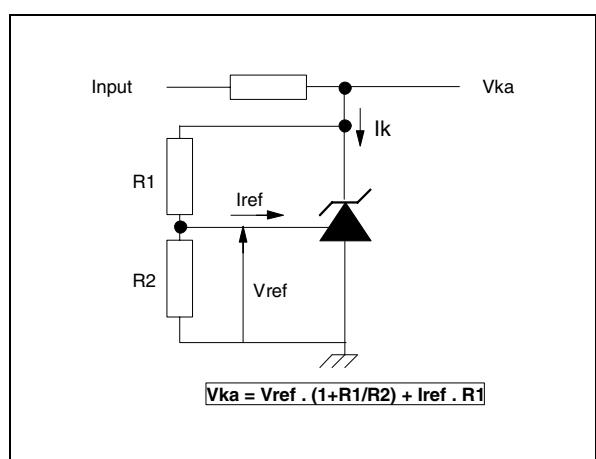
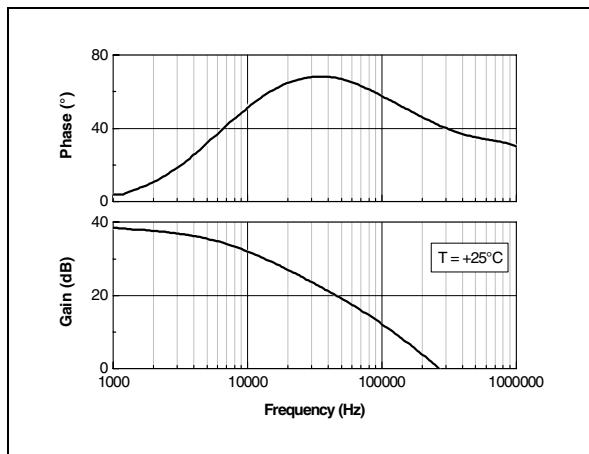
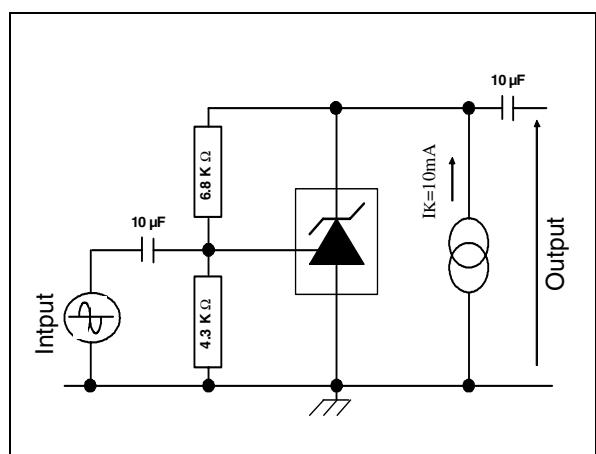
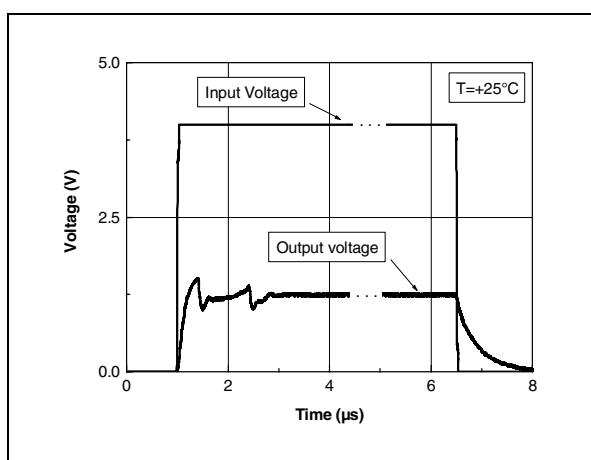
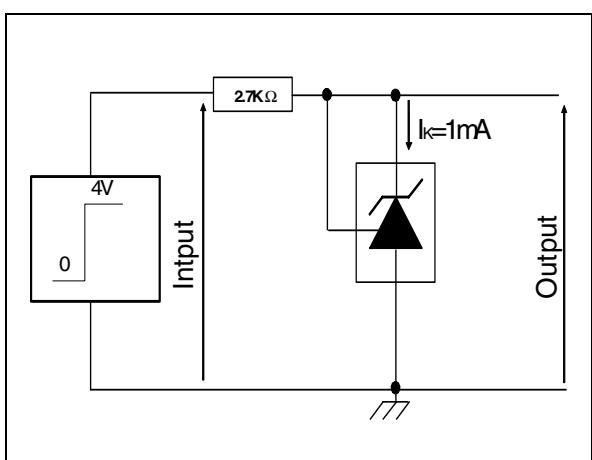
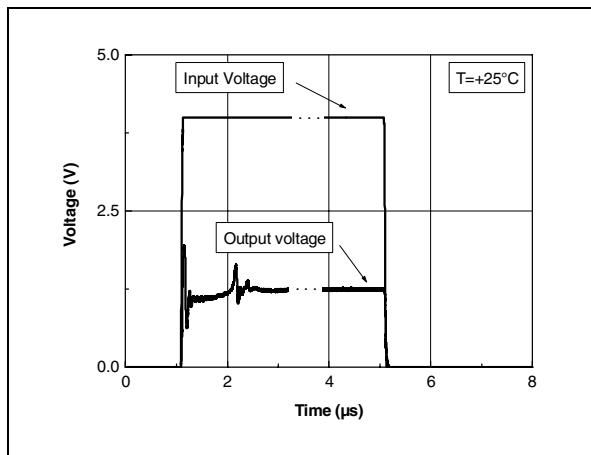
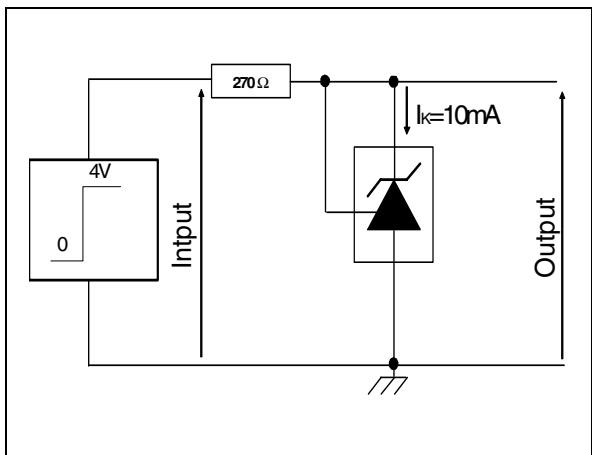
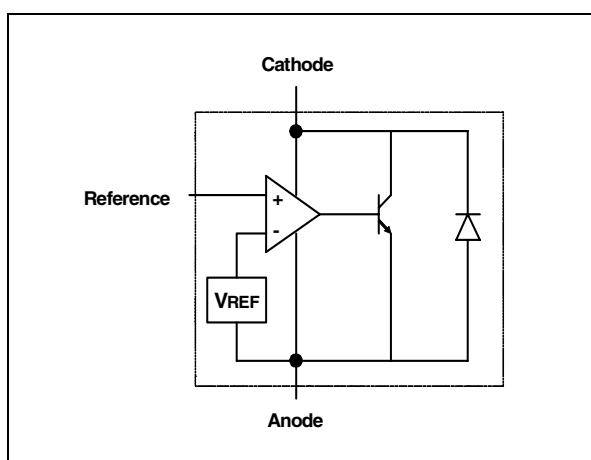
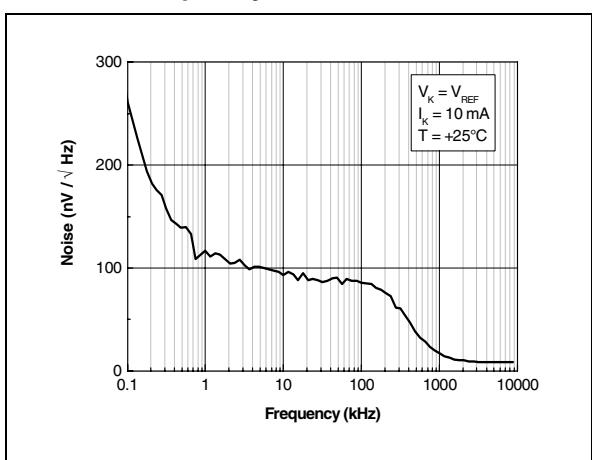
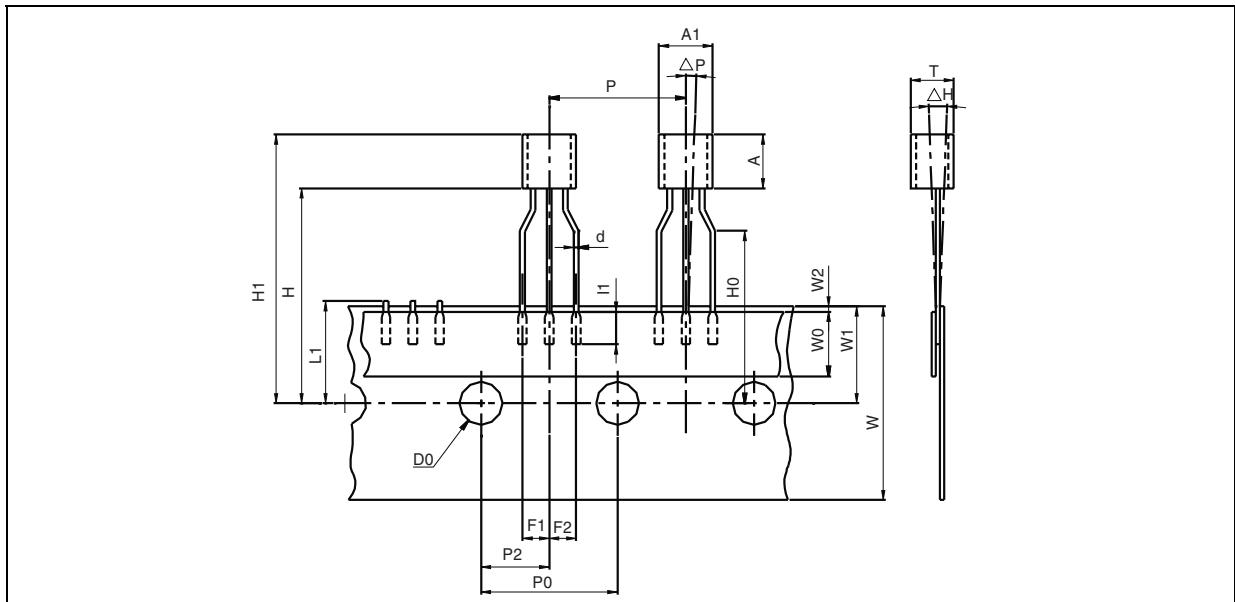
Figure 7. Off-State current vs temperature**Figure 10. Test circuit for off-state current measurement****Figure 8. Ratio of change in reference input voltage to change in Vka voltage vs temperature****Figure 11. Test circuit for $V_K > V_{REF}$** **Figure 9. Phase and gain vs frequency****Figure 12. Test circuit for phase and gain measurement**

Figure 13. Pulse response at $I_K=1\text{mA}$ **Figure 16. Test circuit for pulse response at $I_K = 1\text{mA}$** **Figure 14. Pulse response at $I_K = 10\text{mA}$** **Figure 17. Test circuit for pulse response at $I_K = 10\text{mA}$** **Figure 15. Block diagram****Figure 18. Equivalent input noise vs frequency**

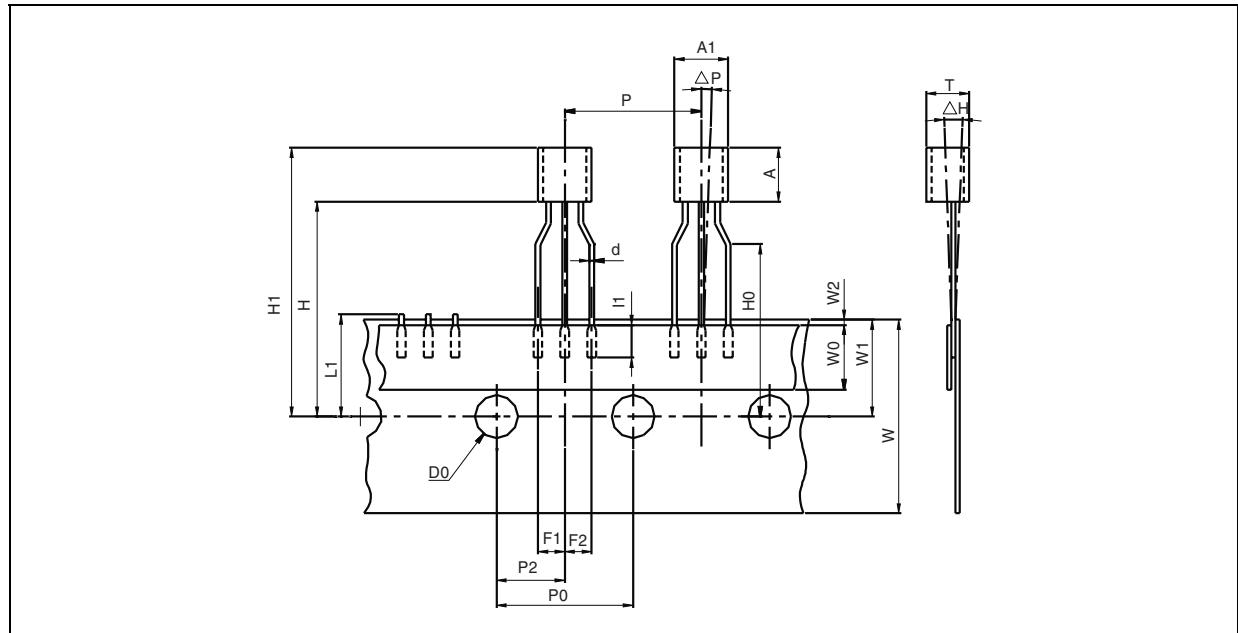
3 Package Mechanical Data

3.1 3 Pins - Plastic Package TO-92 (tape & reel)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
AL			5.0			0.197
A			5.0			0.197
T			4.0			0.157
d		0.45			0.018	
I1	2.5			0.098		
P	11.7	12.7	13.7	0.461	0.500	0.539
PO	12.4	12.7	13	0.488	0.500	0.512
P2	5.95	6.35	6.75	0.234	0.250	0.266
F1/F2	2.4	2.5	2.8	0.094	0.098	0.110
Δh	-1	0	1	-0.039	0	0.039
ΔP	-1	0	1	-0.039	0	0.039
W	17.5	18.0	19.0	0.689	0.709	0.748
W0	5.7	6	6.3	0.224	0.236	0.248
W1	8.5	9	9.75	0.335	0.354	0.384
W2			0.5			0.020
H			20			0.787
H0	15.5	16	16.5	0.610	0.630	0.650
H1			25			0.984
DO	3.8	4.0	4.2	0.150	0.157	0.165
L1			11			0.433

3.2 3 Pins - Plastic Package TO-92 (tape ammo pack)

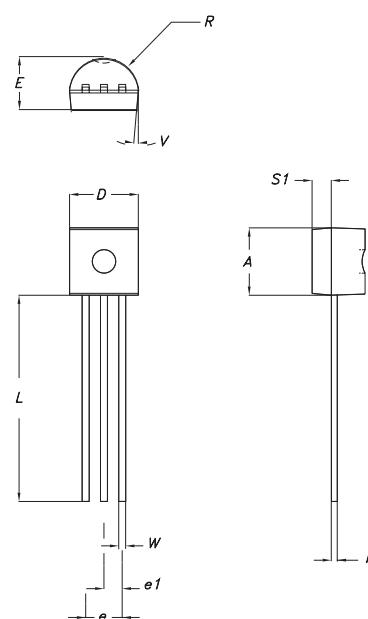


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F1/F2	2.4	2.5	2.8	0.094	0.098	0.110
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ΔP	-1	0	1	-0.039	0	0.039
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W0	5.7	6	6.3	0.224	0.236	0.248
W1	8.5	9	9.75	0.335	0.354	0.384
W2			0.5			0.020
H		20				0.787
H0	15.5	16	16.5	0.610	0.630	0.650
H1			25			0.984
D0	3.8	4.0	4.2	0.150	0.157	0.165
L1			11			0.433

3.3 3 Pins - Plastic Package TO-92 (bulk)

TO-92 MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	4.32		4.95	170.1		194.9
b	0.36		0.51	14.2		20.1
D	4.45		4.95	175.2		194.9
E	3.30		3.94	129.9		155.1
e	2.41		2.67	94.9		105.1
e1	1.14		1.40	44.9		55.1
L	12.7		15.49	500.0		609.8
R	2.16		2.41	85.0		94.9
S1	0.92		1.52	36.2		59.8
W	0.41		0.56	16.1		22.0

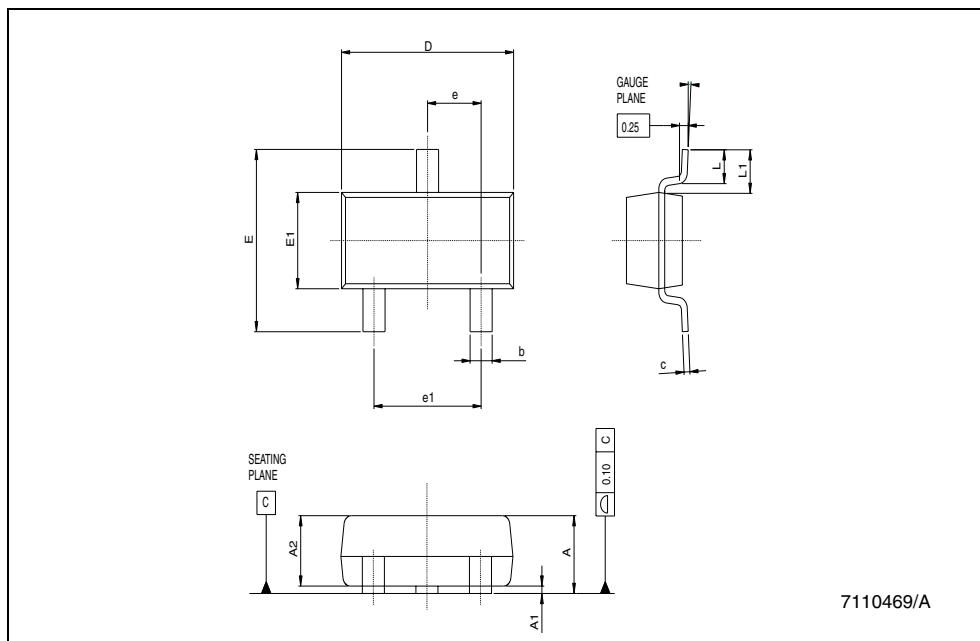


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3.4 SOT23-3L Package

SOT23-3L MECHANICAL DATA

DIM.	mm.			mils		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	0.890		1.120	35.05		44.12
A1	0.010		0.100	0.39		3.94
A2	0.880	0.950	1.020	34.65	37.41	40.17
b	0.300		0.500	11.81		19.69
C	0.080		0.200	3.15		7.88
D	2.800	2.900	3.040	110.26	114.17	119.72
E	2.100		2.64	82.70		103.96
E1	1.200	1.300	1.400	47.26	51.19	55.13
e		0.950			37.41	
e1		1.900			74.82	
L	0.400		0.600	15.75		23.63
L1		0.540			21.27	
k			8°			8°



4 Revision History

Date	Revision	Description of Changes
01 Jan. 2004	1	First Release
01 Dec. 2004	2	Specific content changes as follows: <ul style="list-style-type: none">• CI version added in <i>Table: Order Codes</i> on page 1• Rthjc information added in <i>Table1: Key parameters and their absolute maximum ratings</i> on page 2• Test condition added in <i>Table3: Tamb = 25°C (unless otherwise specified)</i> on page 3

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